
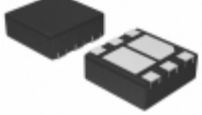






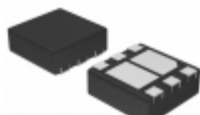
	<h2>NSV60600MZ4T1G</h2>
	<p>Hersteller-Teilenummer: NSV60600MZ4T1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: TRANS PNP 60V 6A SOT223-4</p> <hr/> <p>Datenblätter:  NSV60600MZ4T1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 13238 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NSV60600MZ4T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PNP 60V 6A SOT223-4
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	13238 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	800mW
Verpackung / Gehäuse	TO-261-4, TO-261AA
Supplier Device-Gehäuse	SOT-223-3
Transistor-Typ	PNP
Strom - Kollektor (Ic) (max)	6A
Spannung - Kollektor-Emitter-Durchbruch (max)	60V
VCE Sättigung (Max) @ Ib, Ic	350mV @ 600mA, 6A
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	120 @ 1A, 2V
Frequenz - Übergang	100MHz
Verpackung	Tape & Reel (TR)

NSV60600MZ4T1G ist neu im Original, Suche NSV60600MZ4T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSV60600MZ4T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSV60600MZ4T1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSV60100DMTWTBG AMI Semiconductor / ON Semiconductor DUAL TRANSISTOR PNP</p>	 <p>NSV9435T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 0.72W SOT223-4</p>	 <p>NSV60601MZ4T1G AMI Semiconductor / ON Semiconductor TRANS NPN 60V 6A SOT-223-4</p>	 <p>NSV60600MZ4T3G AMI Semiconductor / ON Semiconductor TRANS PNP 60V 6A SOT223-4</p>
 <p>NSV60601MZ4T3G AMI Semiconductor / ON Semiconductor TRANS NPN 60V 6A SOT-223-4</p>	 <p>NSV60200LT1G AMI Semiconductor / ON Semiconductor TRANS PNP 60V 2A SOT23-3</p>	 <p>NSVA278 903MHZ JRC JRC SMD</p>	 <p>NSV60101DMTWTBG AMI Semiconductor / ON Semiconductor TRANS NPN DUAL 60V 1A 6WDFN</p>

heiße Teile

Mehr

NSV12100XV6T1G	NSV12200LT1G	NSV12201LT1G	NSV1C200LT1G	NSV1C200MZ4T1G
NSV1C201LT1G	NSV1C201MZ4T1G	NSV1C300ET4G	NSV1C301ET4G	NSV20200LT1G
NSV20201LT1G	NSV40200LT1G	NSV40201LT1G	NSV40300MZ4T1G	NSV40301MZ4T1G
NSV60200LT1G	NSV60201LT1G	NSV60601MZ4T1G	NSVBAS19LT1G	NSVBAS21HT1G
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NSVBAT54SWT1G	NSVBAT54WT1G	NSVBAV23CLT1G	NSVBAV70TT3G	NSVBAV99WT3G
NSVBC114EPDXV6T1G	NSVBC817-40WT1G	NSVBC818-40LT1G	NSVBC848BWT1G	NSVBC848CLT1G
NSVBC849BLT1G	NSVBC850BLT1G	NSVBC850CLT1G	NSVBC857CWT1G	NSVBC858AWT1G
NSVBC858BLT1G	NSVBC858CLT1G	NSVBCP69T1G	NSVBCW68GLT1G	NSVBCX17LT1G

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